



Simulation Study for CEPC Fast Luminosity Detector based on 4H-SiC

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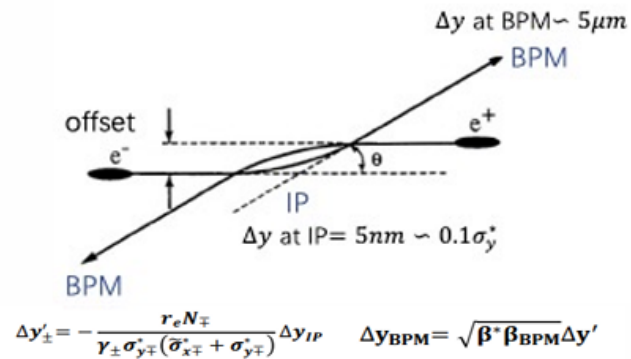
4.Lanzhou University

- Description for CEPC Fast Luminosity Monitor System
- Introduction for 4H-SiC detector
- Simulation Discussion for CEPC Fast Luminosity Detector
- Beam-Beam Deflection and Background Concerns for CEPC Fast Luminosity Detector
- Conclusion and Next to do

Description for CEPC Fast Luminosity Monitor System

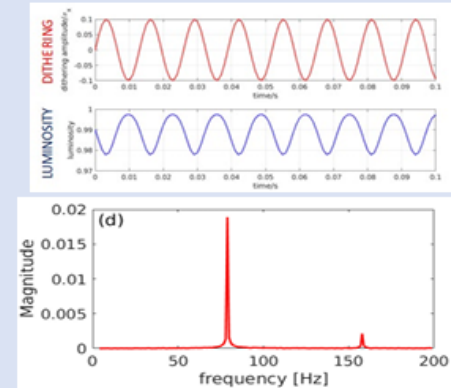
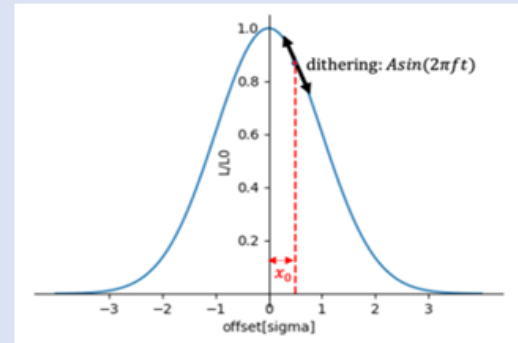
- Crab-waist scheme for CEPC to achieve high luminosity
 - Beam size very small (horizontal: 14 μm ; vertical: 36 nm)
 - Luminosity sensitive to the stability of beam jitter (like ground motion)
- Orbit feedback system at IP to maintain an optimum collision and maximize the luminosity
- Two possible methods for IP orbit feedback system

Vertical IP orbit feedback—Beam-beam deflection driven method



Based on the measurement of the offset with BPMs upstream and downstream of the IP

Horizontal IP orbit feedback—Luminosity driven method

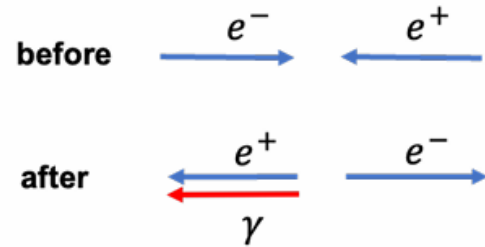


Based on the measurements of the luminosity with a certain frequency dithering

Description for CEPC Fast Luminosity Monitor System

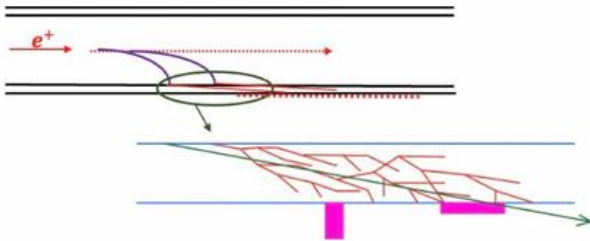
- The fast luminosity monitor based on radiative Bhabha at vanishing photon degree

- Very large cross section (127mbarn)
- Bhabha particles produced at the IP are proportional to the luminosity

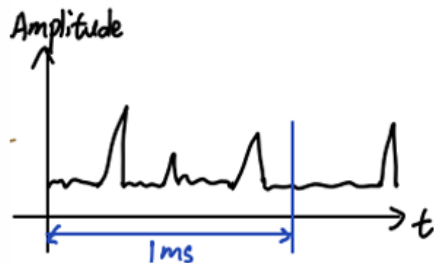


Luminosity	Cross section	Number of Bhabha	Aimed precision	Required fraction
5×10^{34}	0.127 barn	6.35×10^6 in 1ms	2% in 1ms	4×10^{-4}

- The low energy Bhabha electrons hit the beam pipe downstream of IP



- The detectors put outside the beam pipe to capture secondary particles and provide the luminosity information



$$N = \sigma \times \mathcal{L} \times \tau \times \epsilon \quad v = \frac{1}{\sqrt{N}}$$

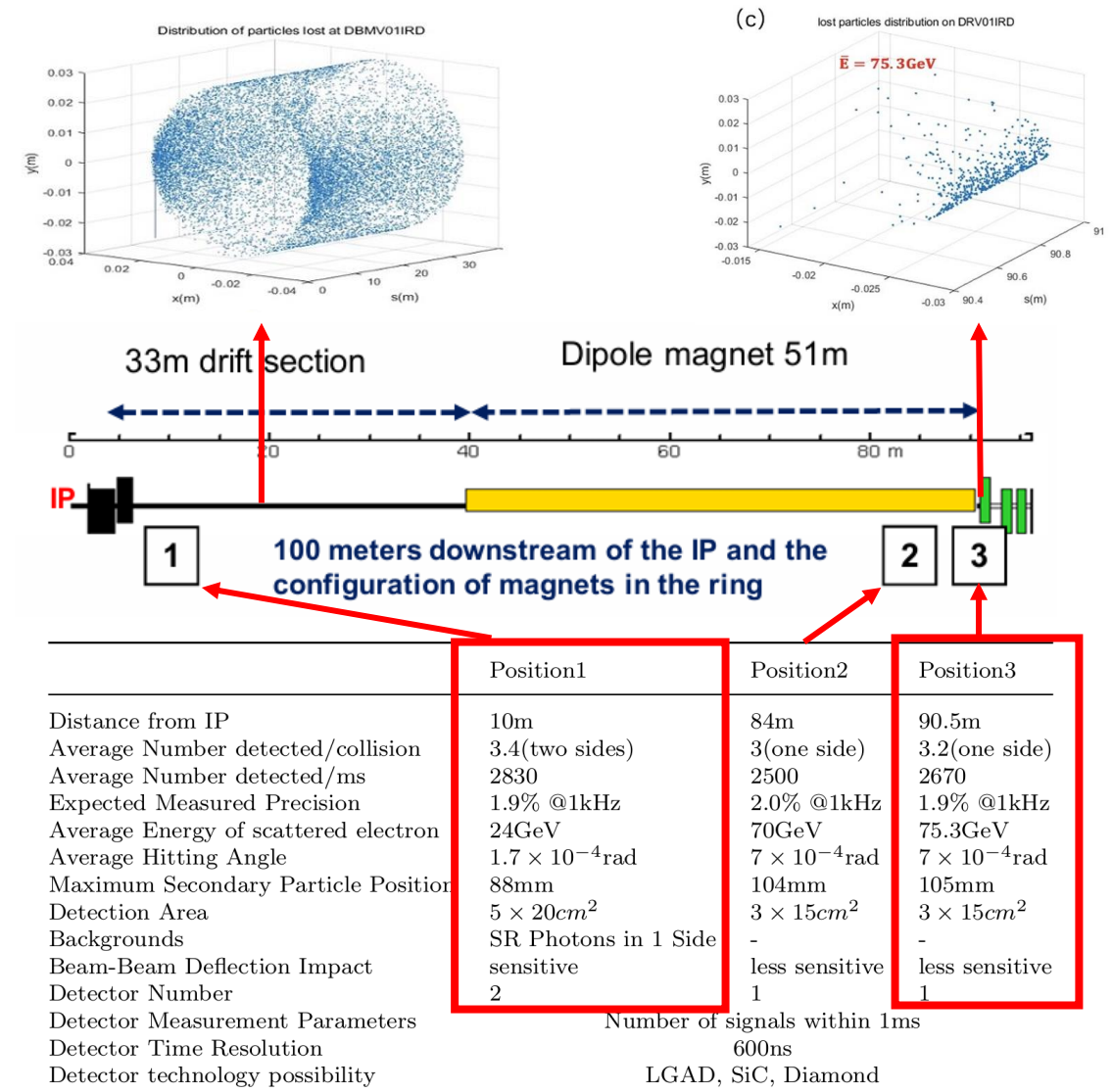
Description for CEPC Fast Luminosity Monitor System

- Downstream of IP 100 m :

- 3 quadrupoles (strong defocusing in the horizontal direction)
- 33 m drift section (some low-energy electrons are likely to be lost)
- 51 m dipole magnet (deflects electrons towards inner side)
- Additional drift sections, magnets and other elements....

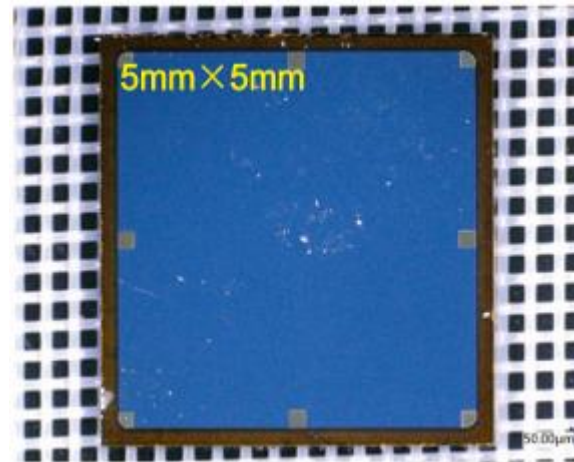
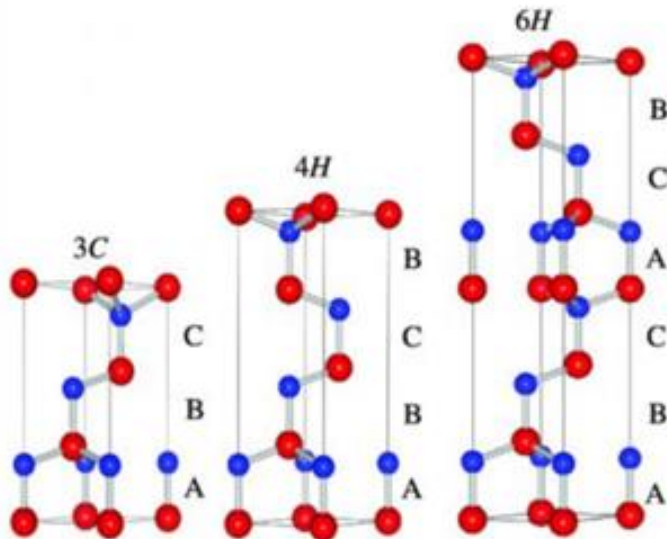
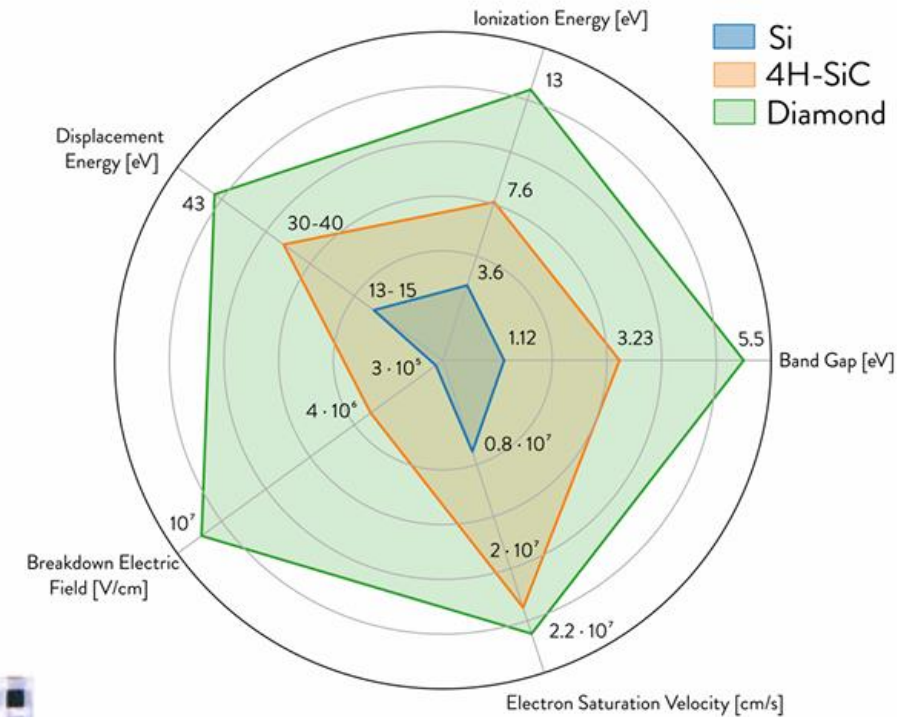
- Detector installed position:

- Position 1 and Position 3
- Position 2 inside the dipole magnet (spatial constraints)



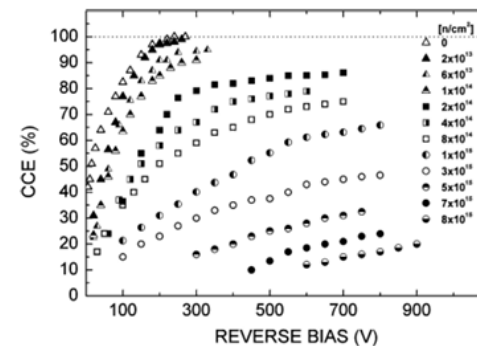
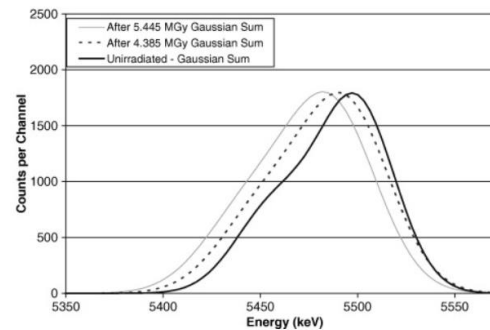
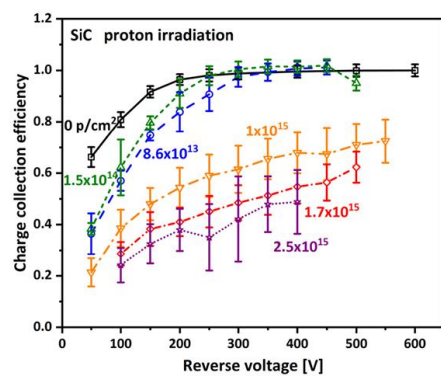
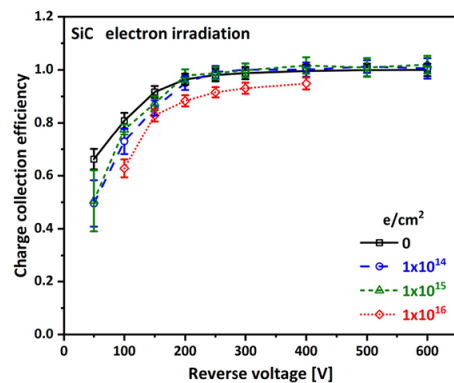
Introduction for 4H-SiC detector

- Wide bandgap semiconductor (3.26 eV)
 - low leakage current
 - insensitivity to visible light
 - high breakdown field and saturation velocity
 - potentially higher radiation hardness, no cooling needed
 - high ionization energy
 - limitations in epitaxial layer thickness and resistivity
- Material not new but now available in higher quality (MOS technologies)



Introduction for 4H-SiC detector

- Under 5.445 MGy gamma irradiation:
 - The full width at half maximum (FWHM) of the peak increased by 17%
 - The energy shifted by 0.24% relative to the unirradiated detector for the ^{238}Pu alpha source.
 - Both of these changes are negligible
- Electron irradiation at 2 MeV:
 - $1 \times 10^{16} \text{ e/cm}^2$: CCE decreases to 90%
- Neutron irradiation at 1 MeV:
 - $1 \times 10^{15} \text{ n/cm}^2$: the diodes maintain the charge collection efficiency (CCE) of 80%
 - $8 \times 10^{15} \text{ n/cm}^2$: CCE decreases to 20%
- Proton irradiation at 24 GeV:
 - $2.5 \times 10^{15} \text{ p/cm}^2$: CCE decreases to 45%
- X-ray irradiation indicate that an irradiation dose of 1 MGy does not affect the performance of the 4H-SiC detector.[Poster D01]



[1]F.H. Ruddy and J.G. Seidel, The effects of intense gamma-irradiation on the alpha-particle response of silicon carbide semiconductor radiation detectors, Nuclear Instruments and Methods in Physics Research Section B: Beam Interactions with Materials and Atoms 263 (2007) 163.

[2]F. Nava, A. Castaldini, A. Cavallini, P. Errani and V. Cindro, Radiation Detection properties of 4H-SiC Schottky Diodes Irradiated up to 10^{16} n/cm^2 by 1 MeV Neutrons, IEEE Transactions on Nuclear Science 53 (2006) 2977.370

[3]J.M. Rafi, G. Pellegrini, P. Godignon, S.O. Ugobono, G. Rius, I. Tsunoda et al., Electron, Neutron, and Proton Irradiation Effects on SiC Radiation Detectors, IEEE Transactions on Nuclear Science 67(2020) 2481.373

Simulation Discussion for CEPC Fast Luminosity Detector

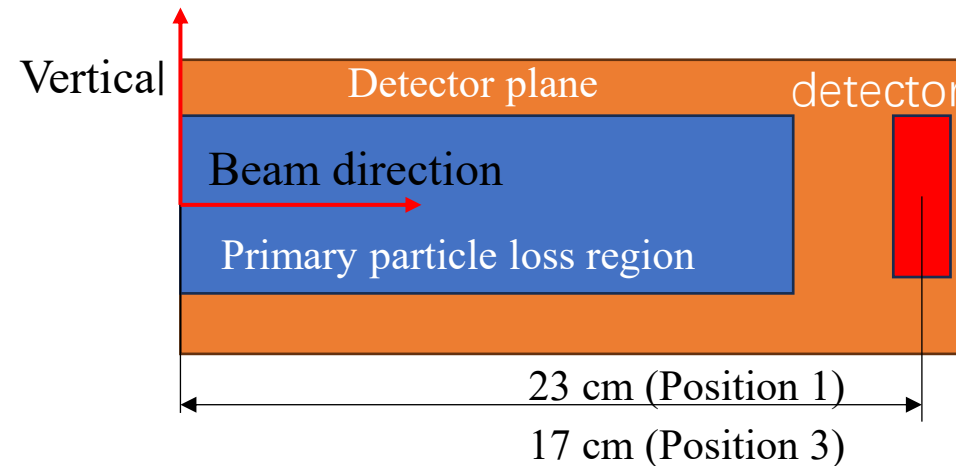
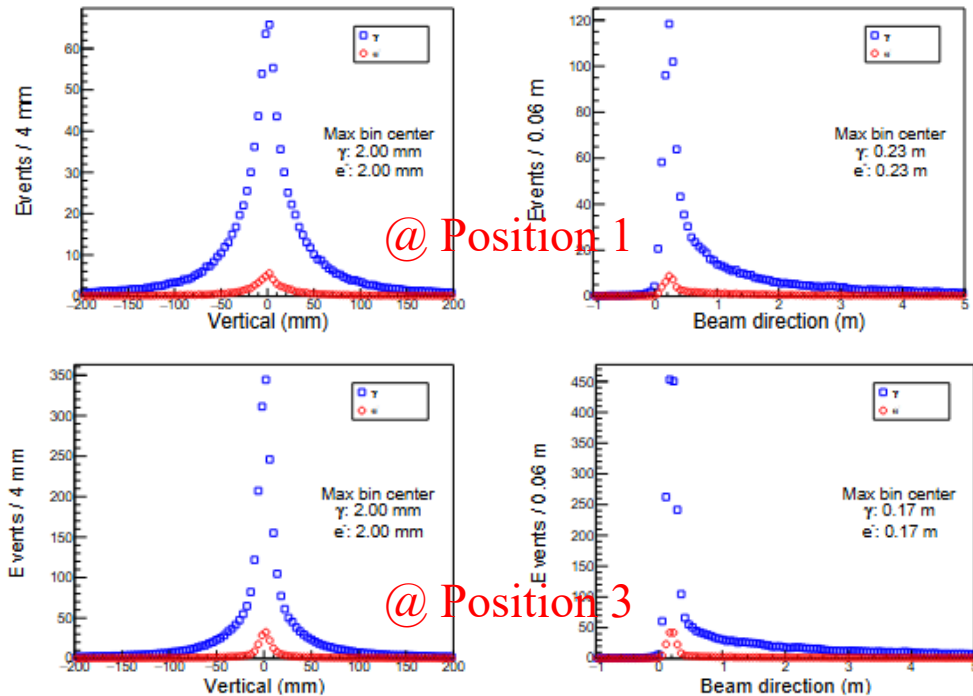
- Secondary particle:

- Generated by the interaction between primary electrons and beam pipe
- Captured by the detector and generates a signal
- Photons dominant (87%), with 7% electrons

- Secondary particle distribution:

- Detector plane: tangent to the outer wall of the beam pipe, ± 31 mm in horizontal, detector mounting plane
- Statistical distribution of secondary particles in the detector plane
- Vertical distribution: symmetrical distribution with respect to the origin
- Beam direction: 23 cm (Position 1) and 17 cm (Position 3) from one end of the primary electron loss region

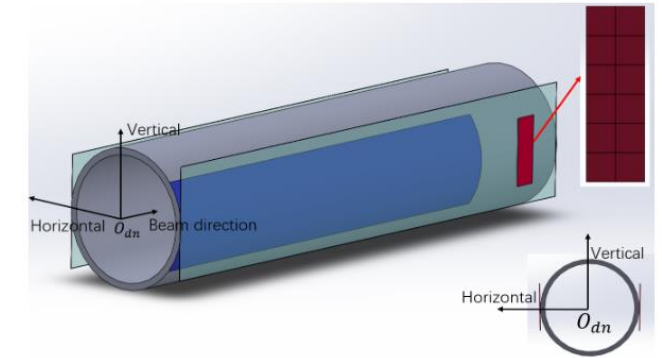
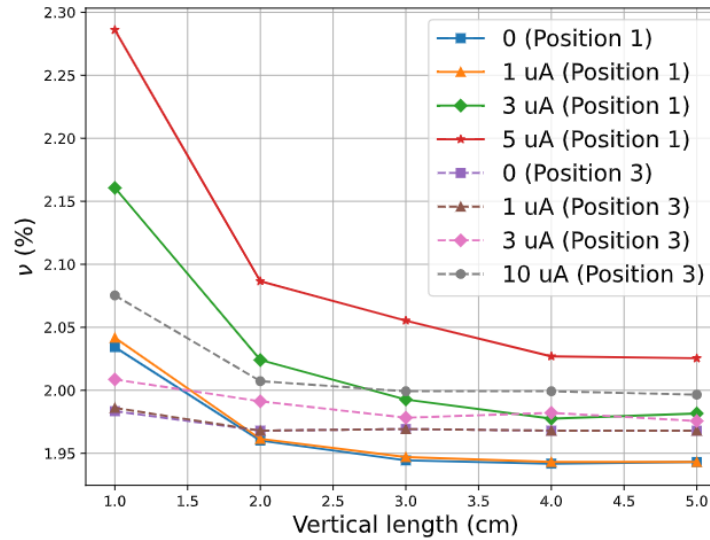
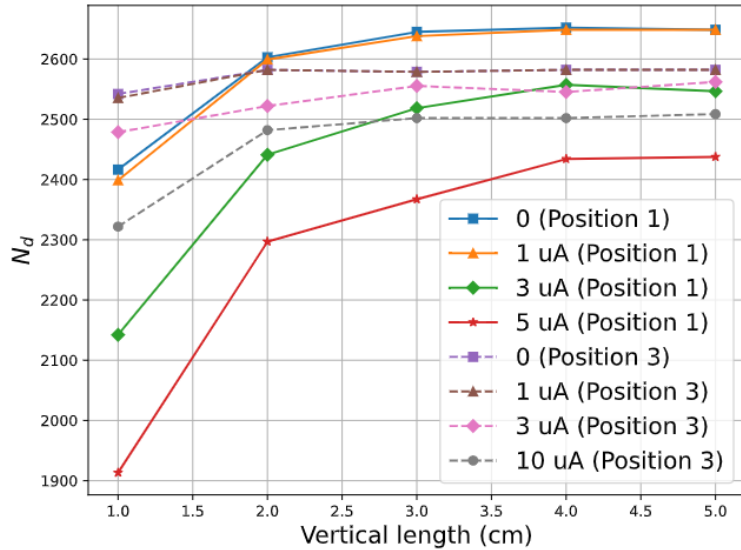
Secondary particle species	$N_{sp}/N_{total}(\%)$ at Position 1		$N_{sp}/N_{total}(\%)$ at Position 3
	-31 mm detector plane	31 mm detector plane	-31 mm detector plane
γ	87.86	87.67	86.93
e^-	7.19	7.32	7.80
others	4.95	5.01	5.27S
total	100	100	100



Simulation Discussion for CEPC Fast Luminosity Detector

- Fast luminosity detector 2% precision requirement:
 - 804 bunch crossing within 1 ms, bunch space: 600 ns (Low power Higgs mode)
 - Average 3.4 and 3.2 particles interact with the beam pipe at position 1 and position 3 per bunch crossing, respectively. (Poisson distribution)
 - Precision $\nu \leq 2\%$, the number of detected Bhabha electrons $N_d \geq 2500$ (within 1 ms)
- Detector dimension optimization:
 - The entire detector is constructed by $5\text{mm} \times 5\text{mm}$ pixels
 - The detector length in the beam-direction is fixed at 1 cm, while the vertical length varies
 - Different equivalent input current noise levels (0, 1uA, 3uA, 5uA, 10uA) are considered

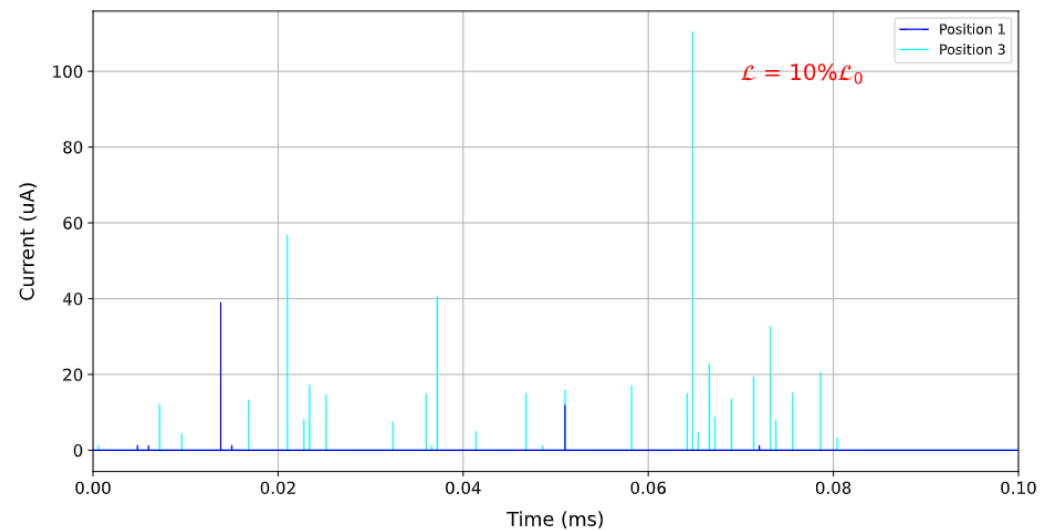
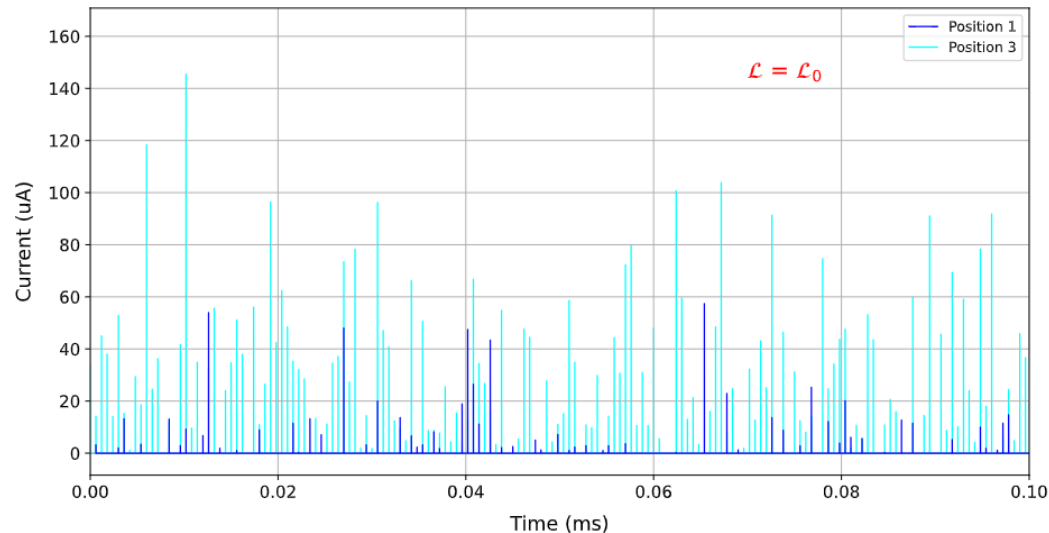
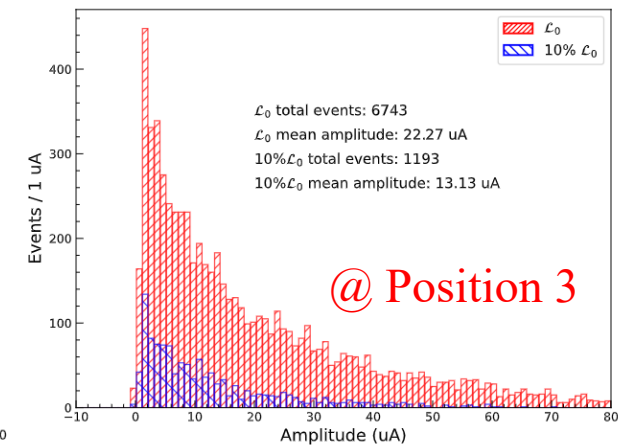
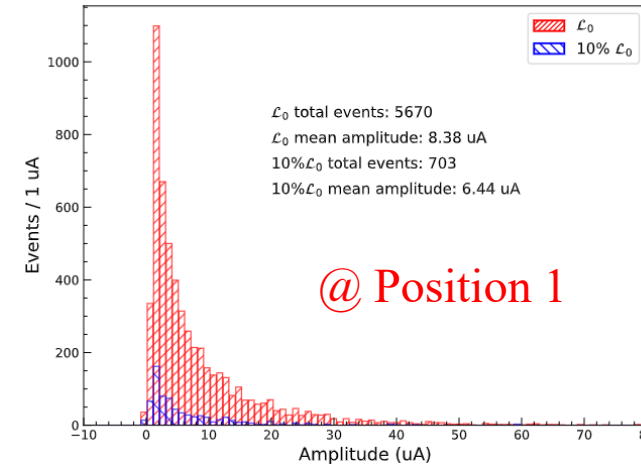
$$\nu = \frac{1}{\sqrt{N_d}} < 2\%$$



- The final determined detector dimension is 1 cm (beam direction) \times 3 cm (vertical length), 12 pixels in total.
- The noise threshold at position 1 is 3 μA , while the noise threshold at position 3 is 10 μA .

Simulation Discussion for CEPC Fast Luminosity Detector

- Luminosity fluctuation → detector' response change
 - For a single pixel, different signal responses at nominal luminosity and 10% of nominal luminosity
 - For the entire detector, significant differences in the number and amplitude of the signals.

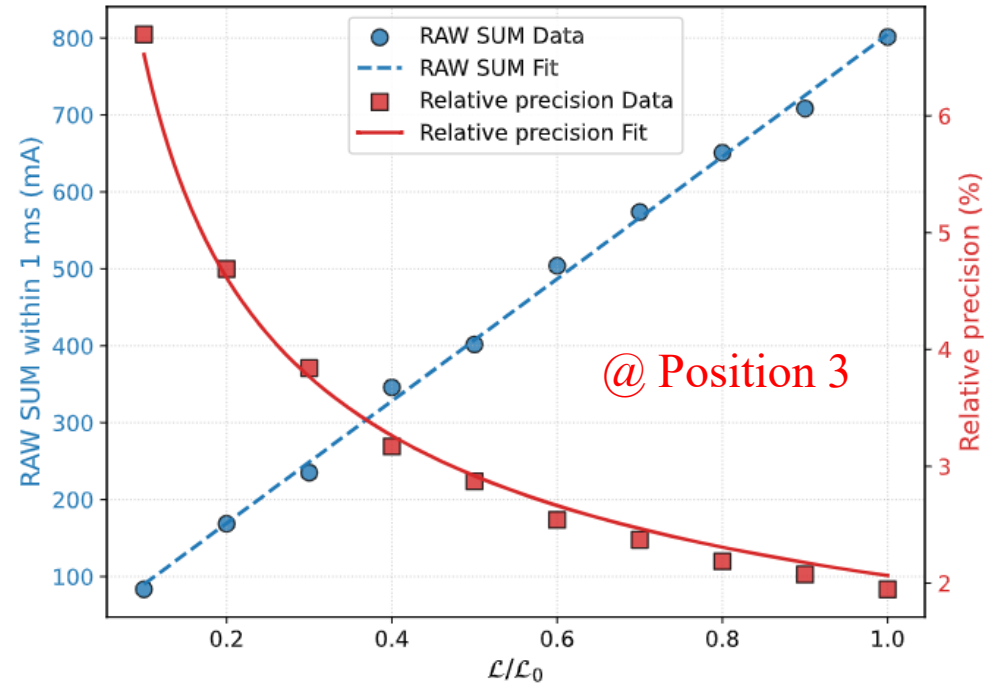
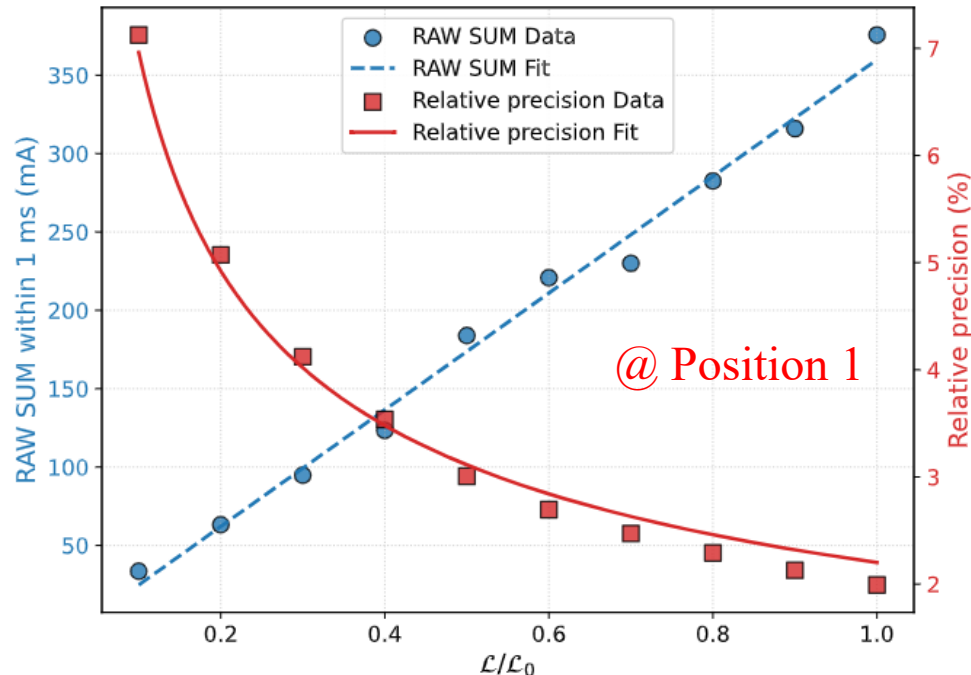


Simulation Discussion for CEPC Fast Luminosity Detector

- The relationship between detector RAW SUM and luminosity
 - Assuming the sampling frequency of the DAQ is 10 GHz
 - Define RAW SUM:
 - s signifies the sampling points within 1 ms
 - p denotes the channel associated with each pixel within the single-sided detector
 - j represents the signals generated by the detectors situated on both sides of the beam pipe at Position 1
- The relative precision under different luminosity conforms to $v \propto \frac{1}{\sqrt{L}}$

$$\text{RAW SUM} = \sum_{j=1}^2 \sum_{s \in \mathcal{S}} \sum_{p \in \mathcal{P}} i_j(s, p) \quad \text{at Position 1}$$

$$\text{RAW SUM} = \sum_{s \in \mathcal{S}} \sum_{p \in \mathcal{P}} i_j(s, p) \quad \text{at Position 3}$$



Beam-Beam Deflection and Background Concerns for CEPC Fast Luminosity Detector

- Beam-Beam Deflection:
 - originates from the electromagnetic interaction between the electron and positron bunches
 - the principle of BPM measurement of the orbit offset
- Beam-Beam Deflection mainly impacts position 1, with almost no effect on position 3
- 10% reduction of detected Bhabha electrons after considering beam-beam deflection(the worst case)
- After considering beam-beam deflection, the detector precision v_b becomes $1.04v$

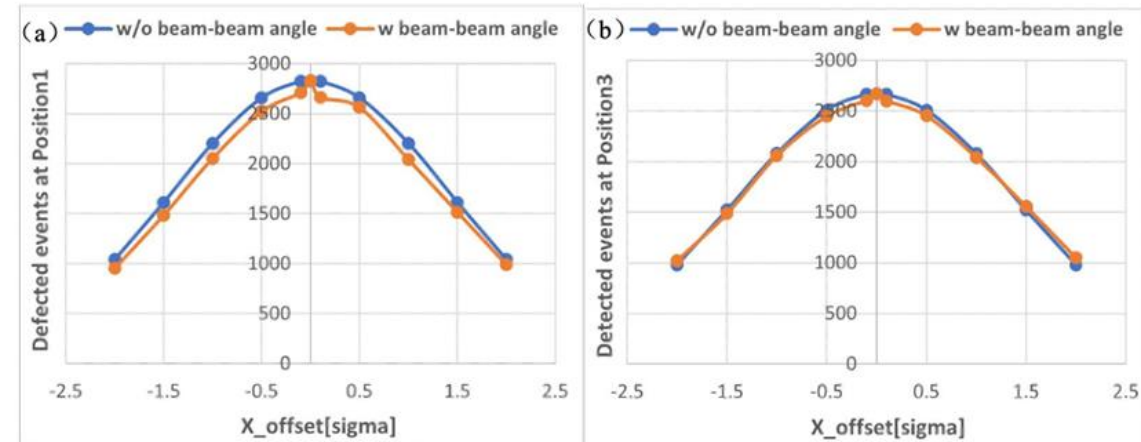
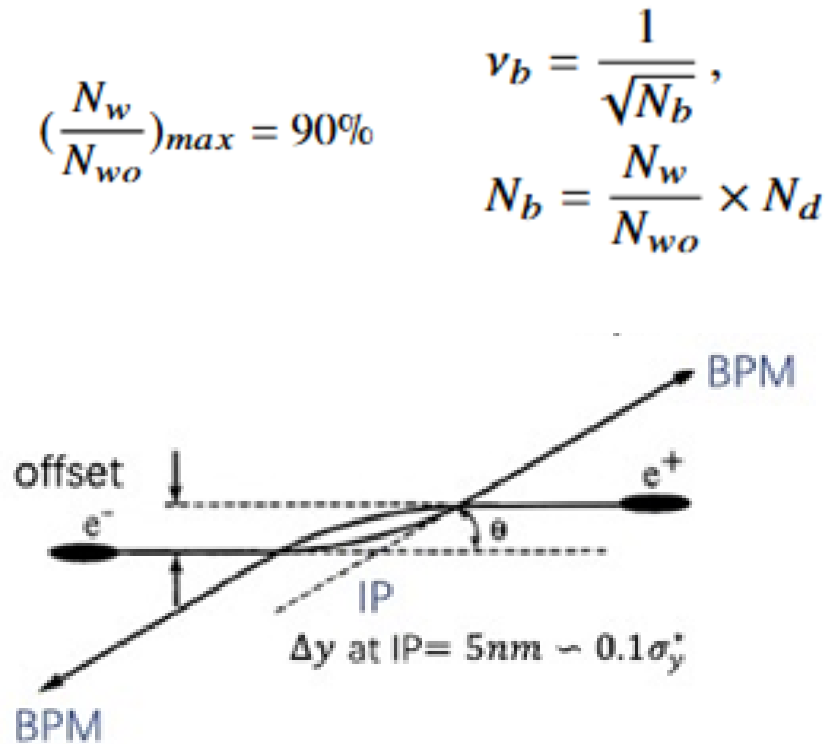


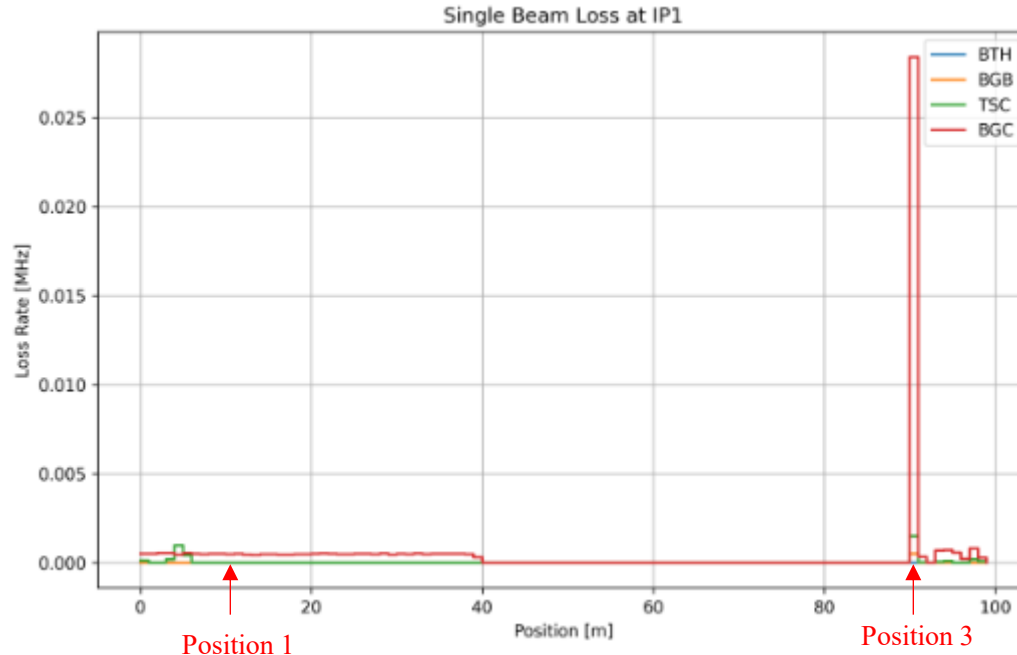
Fig. 12 Expected detected Bhabha events varies with IP offset at Positions 1 and 3

Beam-Beam Deflection and Background Concerns for CEPC Fast Luminosity Detector

● Single-Beam background:

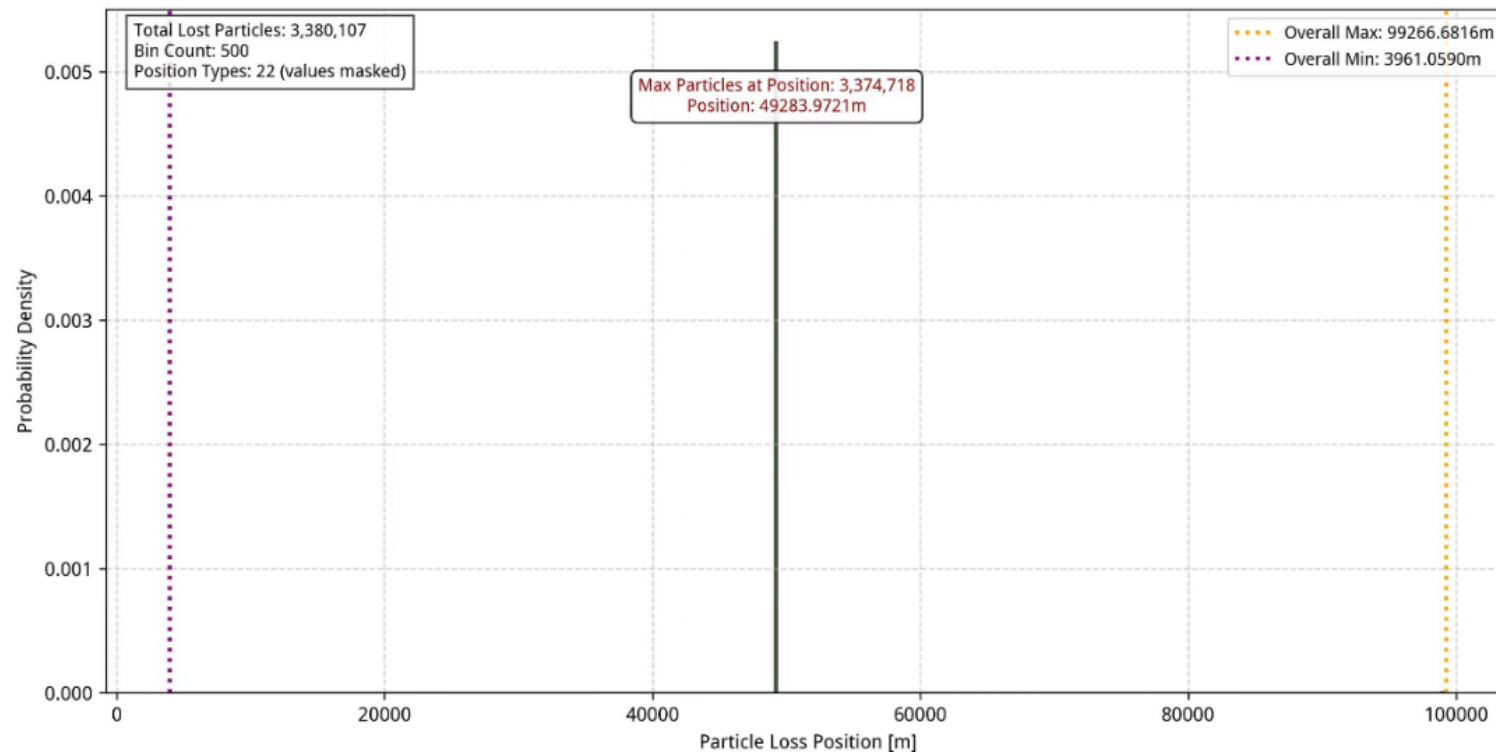
- 4 single-beam background are concerned: beam-thermal photon scattering (BTH), beam-gas scattering (Coulomb scattering (BGC) and Bremsstrahlung scattering (BGB)), and Touschek scattering (TSC)
- BGC dominants, and the single-beam background has losses at position 1 and position 3

	Single-Beam background	Primary electrons by radiative Bhabha
Position 1	7×10^{-5} per bunch crossing	3.4 per bunch crossing
Position 3	2×10^{-2} per bunch crossing	3.2 per bunch crossing



Beam-Beam Deflection and Background Concerns for CEPC Fast Luminosity Detector

- Injection background:
 - Top-up injection
 - Aperture blocks to minimize the impact of injection background on the collision region
 - With beam-beam impact concerned
 - 50 million particles are injected and run around the ring for 200 turns
- Particle loss is mainly concentrated at 49.28 km downstream of the IP, with no loss at position 1 and Position 3(10 m and 90.5 m downstream of the IP)



- Conclusion:

- The dimension ($1\text{ cm} \times 3\text{ cm}$) and position (Position 1 offset 23 cm, Position 3 offset 17 cm) of the detector installation have been determined.
- Detector RAW SUM within 1 ms has a good linear relationship with luminosity, and therefore can be used for real-time luminosity monitoring.
- The impact of Beam-Beam deflection, Single-beam background and Injection background has been concerned

- Next to do:

- 4H-SiC device fabrication and test
- Design for multi-channel ultrafast readout electronics of the detector
- A fast luminosity monitor system prototype and Design validation at BEPCII

Thanks